VS-20L15TPbF, VS-20L15T-N3

Vishay Semiconductors



TO-220AC Base cathode 0 2 0 1 0 3 Cathode Anode

PRODUCT SUMMARY							
Package	TO-220AC						
I _{F(AV)}	20 A						
V _R	15 V						
V_F at I_F	See Electrical table						
I _{RM} max.	600 mA at 100 °C						
T _J max.	125 °C						
Diode variation	Single die						
E _{AS}	10 mJ						

Schottky Rectifier, 20 A

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- Single diode configuration
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- Guard ring for enhanced ruggedness and long
 term reliability
 HALOGEN



- high temperature epoxy enhanced mechanical strength
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	A						
V _{RRM}		15	V						
I _{FSM}	t _p = 5 μs sine	700	A						
V _F	19 A_{pk} , $T_J = 125 \ ^{\circ}C$ (typical)	0.25	V						
TJ	Range	- 55 to 125	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-20L15TPbF	VS-20L15T-N3	UNITS				
Maximum DC reverse voltage	V _R	15	15	V				
Maximum working peak reverse voltage	V _{RWM}	15	15					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 85$ °C,	20					
Maximum peak one cycle non-repetitive surge current	Irou	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	700	A			
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330				
Non-repetitive avalanche energy	E _{AS}	T_J = 25 °C, I_{AS} = 2 A, L = 6 mH	10	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	2	А				

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS				
		19 A	T ₁ = 25 °C	-	0.41	V			
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j=23 0	-	0.52				
See fig. 1	VFM (*)	19 A	T _{.1} = 125 °C	0.25	0.33				
		40 A	- 1j = 125 C	0.37	0.50				
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	-	10	mA			
See fig. 2	IRM ("	T _J = 100 °C	$v_{\rm R} = naleu v_{\rm R}$	-	600	IIIA			
Threshold voltage	V _{F(TO)}	T _ T mov		0.182		V			
Forward slope resistance	r _t	$I_{J} = I_{J} \prod ax.$	$T_J = T_J max.$			mΩ			
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$, (test signal ran	-	2000	pF				
Typical series inductance	L _S	Measured lead to lead 5 m	8	-	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperatu	re range	TJ		- 55 to 125		
Maximum storage temperatur	re range	T _{Stg}		- 50 to 150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.5		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W	
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation (for D ² PAK)	40		
Annualizate uniolet				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum		Nex lubricated threads	6 (5)	kgf · cm (lbf · in)	
Mounting torque —	maximum		Non-lubricated threads	12 (10)		
Marking device			Case style TO-220AC	20L1	I5T	



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Fig. 1 - Maximum Forward Voltage Drop Characteristics



Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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85

80

75

70

0

See note (1)

4

8

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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

12

I_{F(AV)} - Average Forward Current (A)

16

20

24



Fig. 7 - Maximum Non-Repetitive Surge Current



Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6);

 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R

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ORDERING INFORMATION TABLE

ORDERING INFORMATION (Example)									
PREFERRED P/N	PACKAGING DESCRIPTION								
VS-20L15TPbF	50	1000	Antistatic plastic tube						
VS-20L15T-N3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95221				
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224				
	TO-220AC -N3	www.vishay.com/doc?95068				



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TO-220AC

plane

A-

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STMDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
С	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØΡ	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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